

Technical Data Sheet

4.8mm Semi-Lens Silicon PIN Photodiode

PD438B/S46

Features

- Fast response times
- High photo sensitivity
- Small junction capacitance
- Pb free
- The product itself will remain within RoHS compliant version.

Descriptions

PD438B/S46 is a high speed and sensitive PIN photodiode in a flat side view plastic package. The epoxy package itself is an IR filter , spectrally matched to IR emitter.



Applications

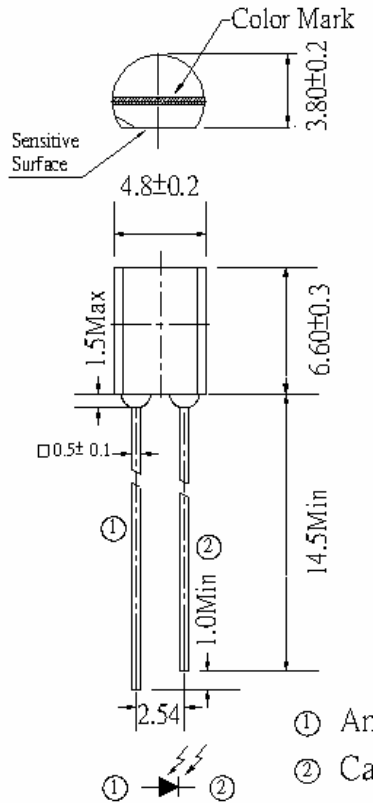
- High speed photo detector
- Camera
- Optoelectronic switch
- VCRs , Video camera

Device Selection Guide

LED Part No.	Chip	Lens Color
	Material	
PD	Silicon	Black



Package Dimensions



- Notes:** 1.All dimensions are in millimeters
 2.Tolerances unless dimensions $\pm 0.25\text{mm}$

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Reverse Voltage	V _R	32	V
Power Dissipation	P _d	150	mW
Lead Soldering Temperature	T _{sol}	260	°C
Operating Temperature	T _{opr}	-40 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +85	°C

Notes: *1:Soldering time ≤ 5 seconds.

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition	Min.	Typ.	Max.	Units
Rang of Spectral Bandwidth	$\lambda_{0.5}$	-----	840	---	1100	nm
Wavelength of Peak Sensitivity	λ_p	-----	---	940	---	nm
Open-Circuit Voltage	V_{OC}	Ee=5m W/cm ² $\lambda_p=940\text{nm}$	---	0.35	---	V
Short- Circuit Current	I_{SC}	Ee=1m W/cm ² $\lambda_p=940\text{nm}$	---	18	---	μA
Reverse Light Current	I_L	Ee=1m W/cm ² $\lambda_p=940\text{nm}$ $V_R=5\text{V}$	10.2	18	---	
Dark Current	I_d	Ee=0m W/cm ² $V_R=10\text{V}$	---	5	30	nA
Reverse Breakdown	BV_R	Ee=0m W/cm ² $I_R=100\ \mu\text{A}$	32	170	---	V
Total Capacitance	C_t	Ee=0m W/cm ² $V_R=3\text{V}$ $f=1\text{MHZ}$	---	25	---	pF
Rise/Fall Time	t_r/t_f	$V_R=10\text{V}$ $R_L=1\text{K}\ \Omega$	---	50/50	---	nS

Typical Electro-Optical Characteristics Curves

Fig.1 Power Dissipation vs. Ambient Temperature

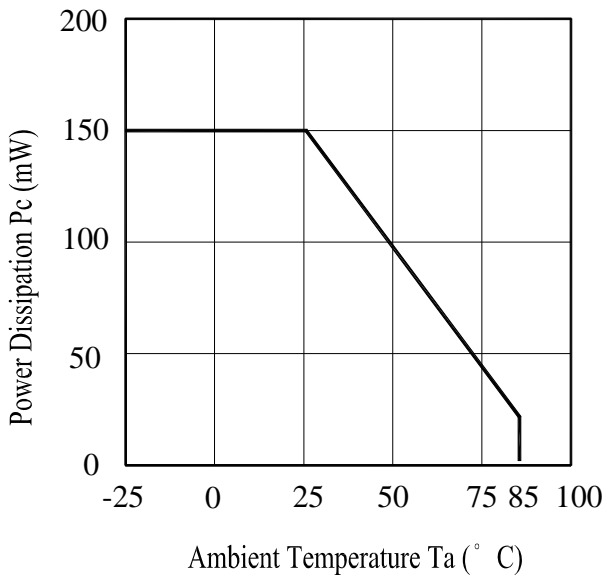


Fig.2 Spectral Sensitivity

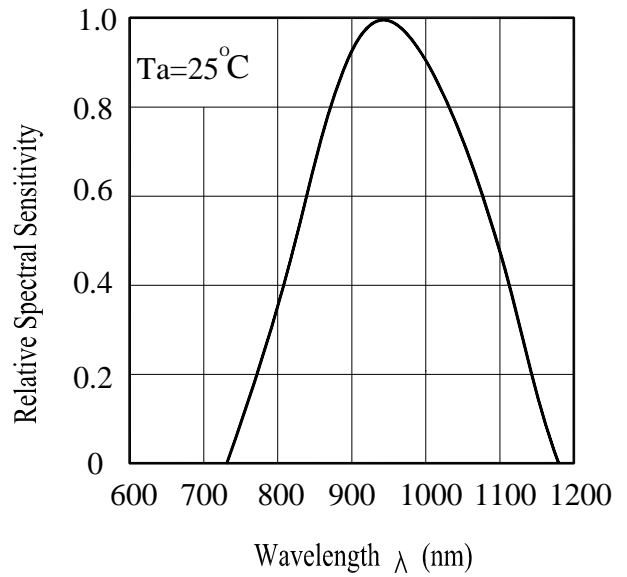


Fig.3 Dark Current vs. Ambient Temperature

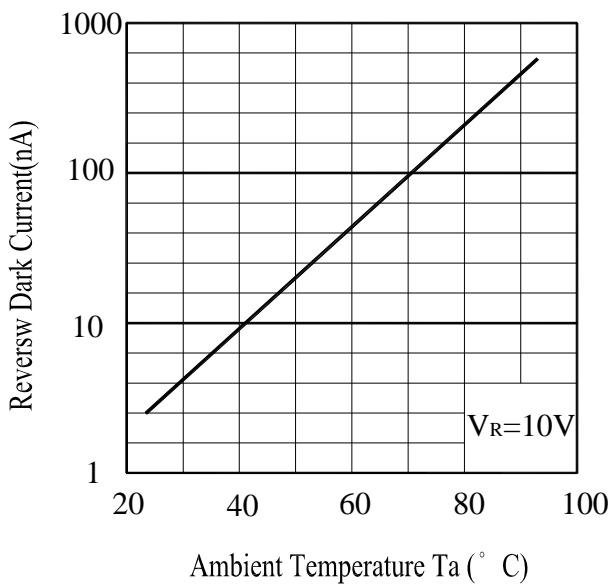
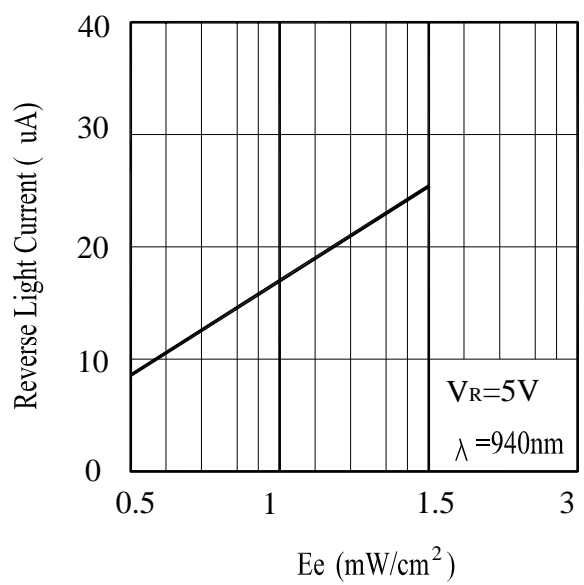


Fig. 4 Reverse Light Current vs. Ee



Typical Electro-Optical Characteristics Curves

Fig.5 Terminal Capacitance vs.
Reverse Voltage

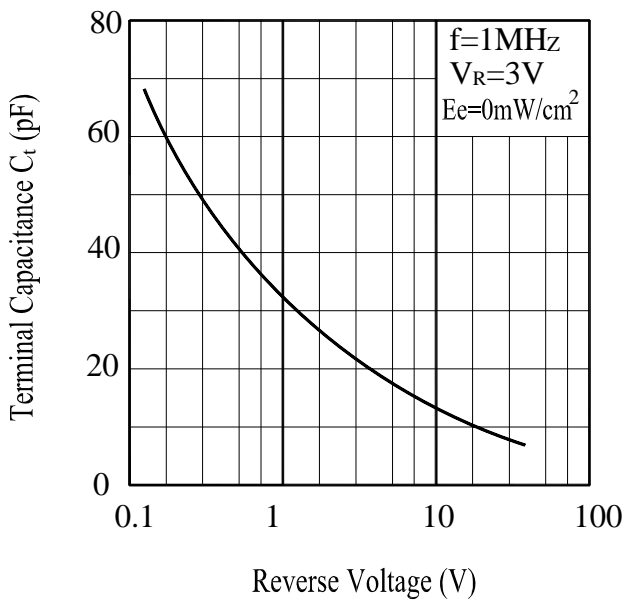
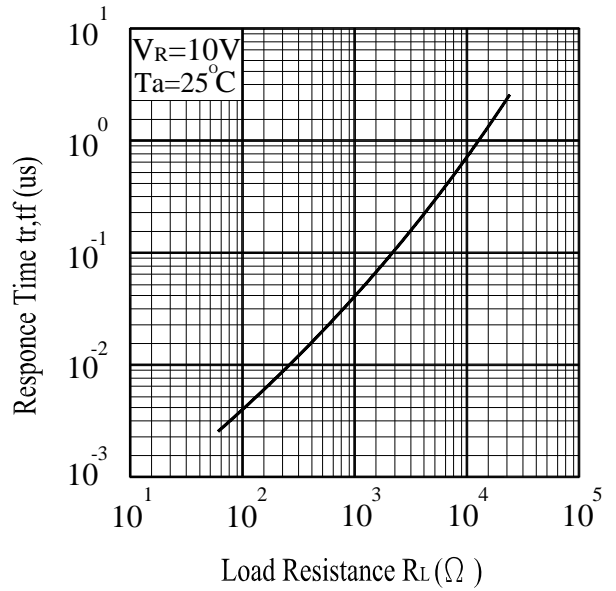


Fig.6 Response Time vs.
Load Resistance



Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD : 10%

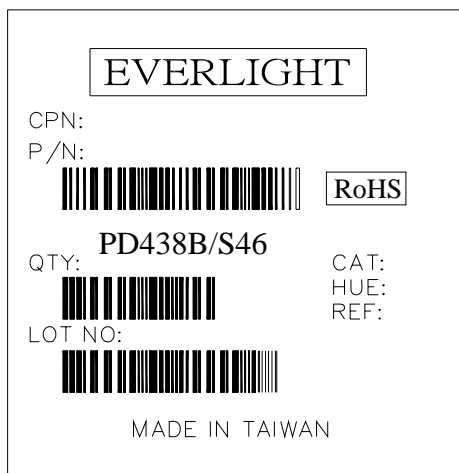
NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgement Criteria	Ac/R e	
1	Solder heat	TEMP. : $260^{\circ}\text{C} \pm 5^{\circ}\text{C}$	10secs	22pcs	Specification Limit	0/1	
2	Temperature Cycle	H : $+100^{\circ}\text{C}$ 15mins ↓ 5mins L : -40°C 15mins	300Cycles	22pcs		$I_L \leq L \times 0.8$ L : Lower	0/1
3	Thermal Shock	H : $+100^{\circ}\text{C}$ 5mins ↓ 10secs L : -10°C 5mins	300Cycles	22pcs		0/1	
4	High Temperature Storage	TEMP. : $+100^{\circ}\text{C}$	1000hrs	22pcs		0/1	
5	Low Temperature Storage	TEMP. : -40°C	1000hrs	22pcs		0/1	
6	DC Operating Life	$V_R = 5\text{V}$	1000hrs	22pcs		0/1	
7	High Temperature/ High Humidity	$85^{\circ}\text{C} / 85\% \text{ R.H}$	1000hrs	22pcs		0/1	

Packing Quantity Specification

1.500PCS/1Bag , 6Bags/1Box

2.10Boxes/1Carton

Label Form Specification



CPN: Customer's Production Number

P/N : Production Number

QTY: Packing Quantity

CAT: Ranks

HUE: Peak Wavelength

REF: Reference

LOT No: Lot Number

MADE IN TAIWAN: Production Place